

Delamination of stiff islands on stretchable substrates

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Int. J. Mater. Res. 98, 717 (2007)

The future of knowledge?

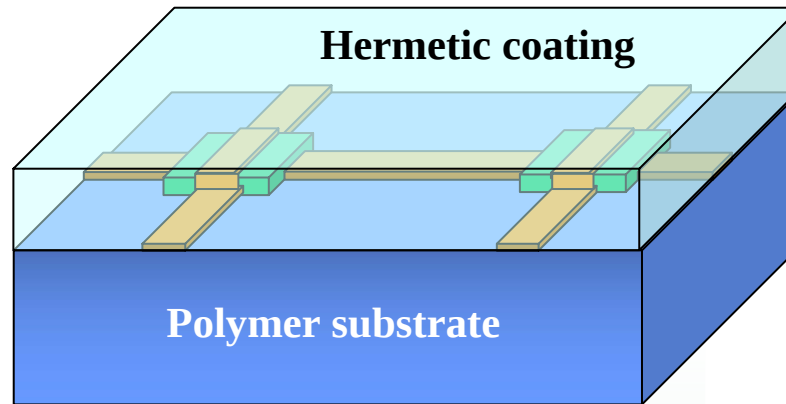
Information



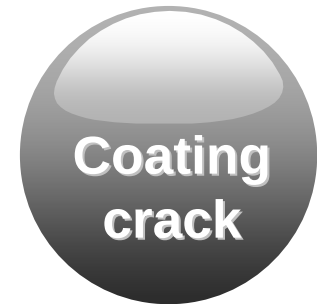
Display



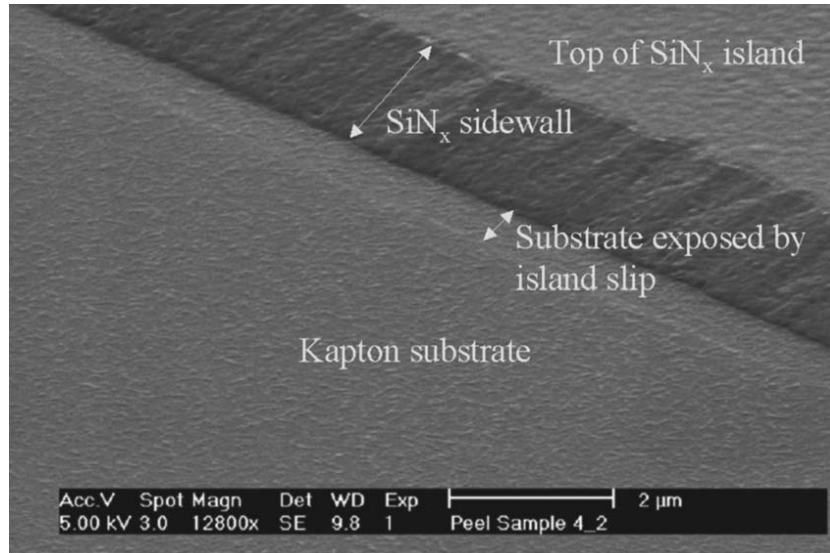
Flexible electronics



*Mechanical
Challenges*



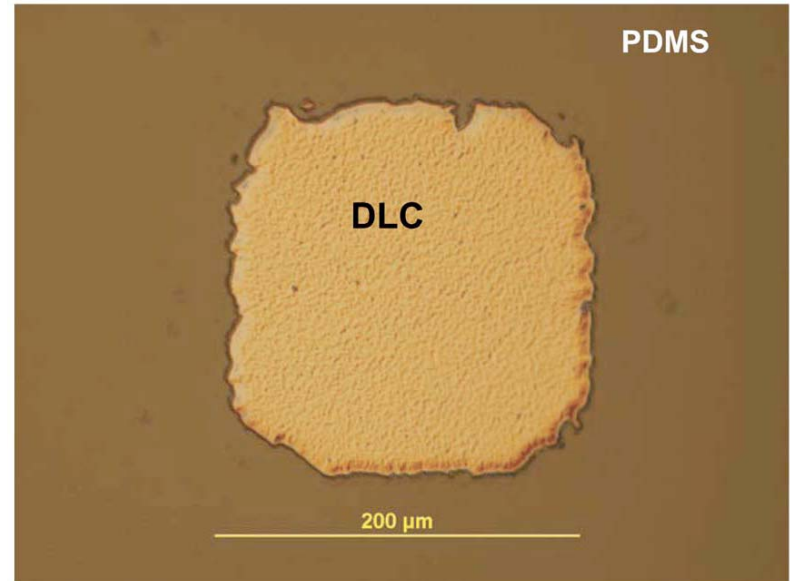
Island debond



$40 \times 40 \mu\text{m}^2$ SiN_x square islands

Debond at 5.6% strain

$$\frac{E_{\text{Kapton}}}{E_{\text{SiN}_x}} = \frac{5\text{GPa}}{200\text{GPa}} = 0.025$$

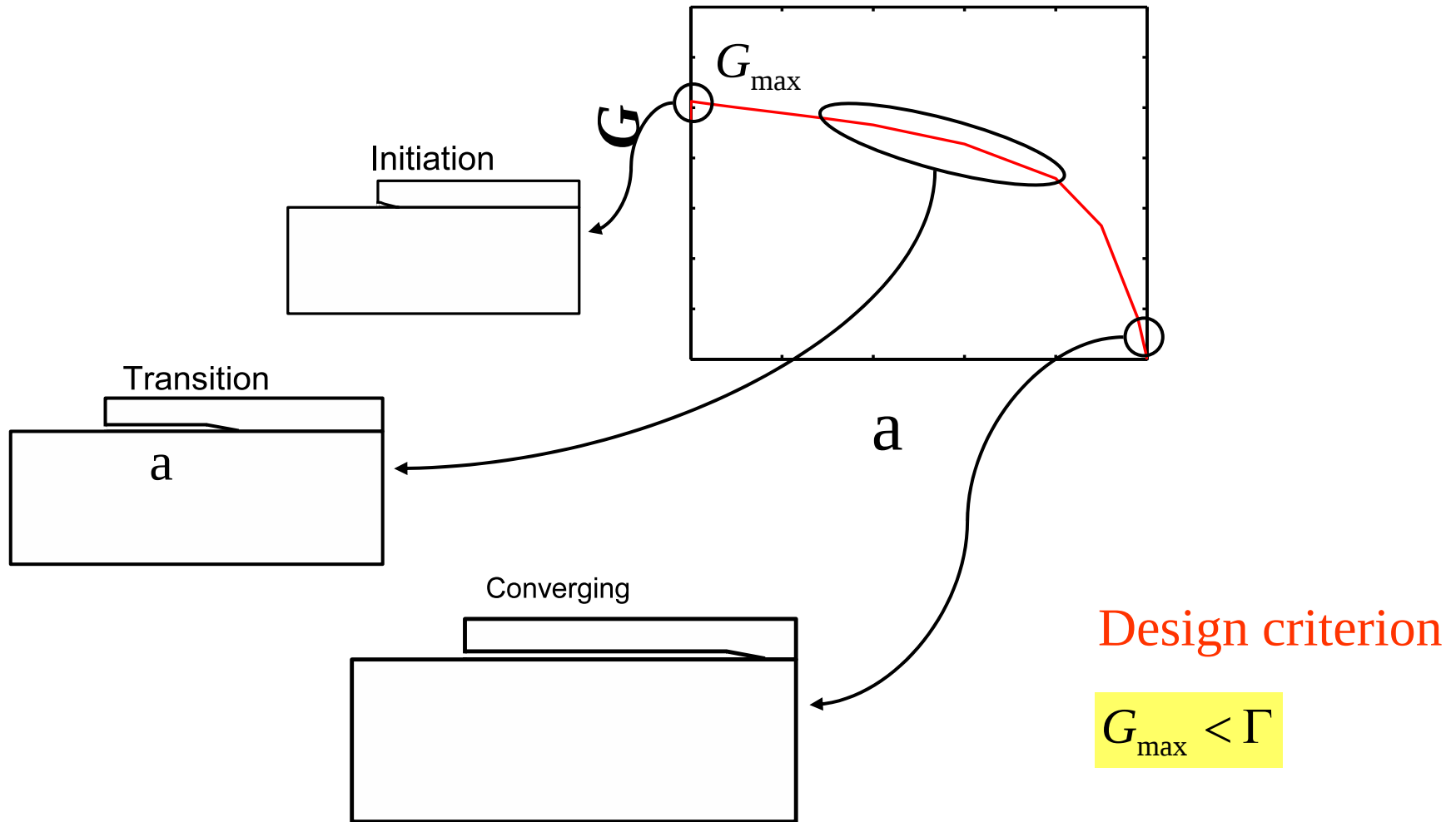


$200 \times 200 \mu\text{m}^2$ DLC square islands

No debond at 25% strain

$$\frac{E_{\text{PDMS}}}{E_{\text{DLC}}} = \frac{1\text{MPa}}{100\text{GPa}} = 1 \times 10^{-5}$$

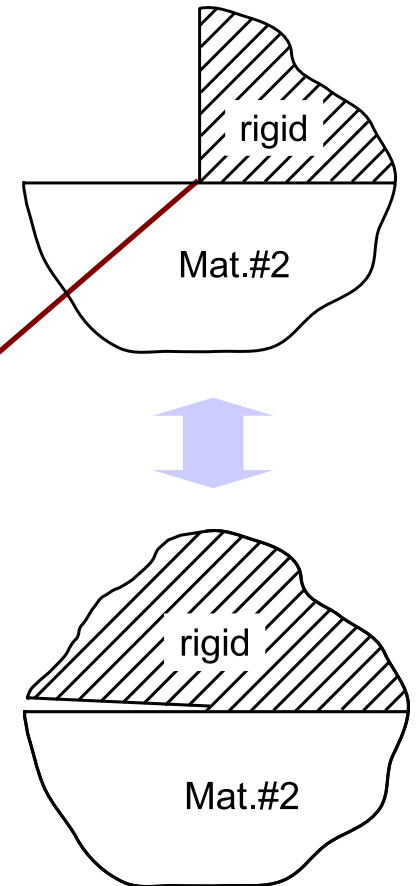
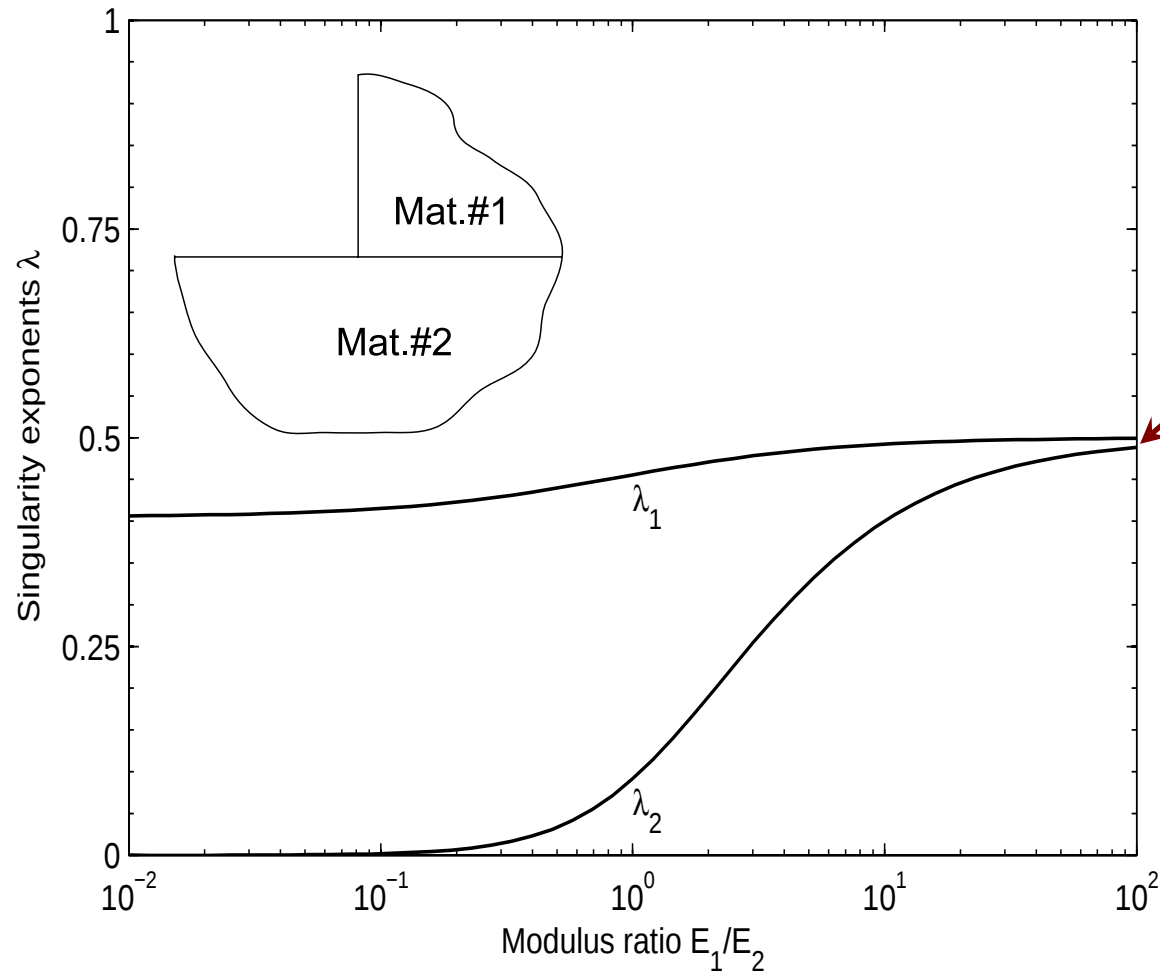
Energy release rate depends on flaw size



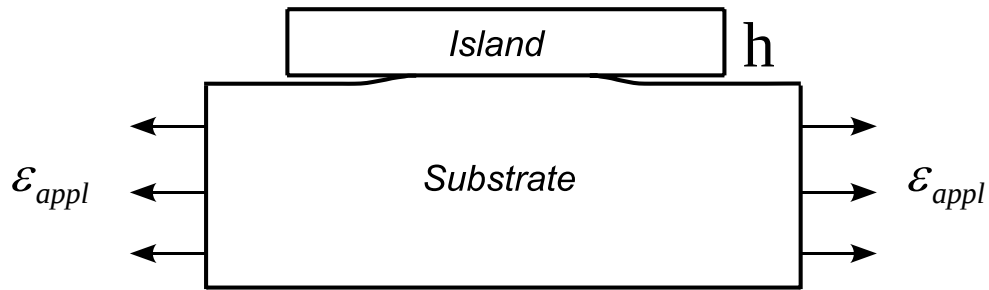
Initiation

$$\sigma_{ij}(r, \theta) = \frac{k_1}{r^{\lambda_1}} \Sigma_{ij}^1(\theta) + \frac{k_2}{r^{\lambda_2}} \Sigma_{ij}^2(\theta)$$

$$G \sim a^{1-2\lambda}$$



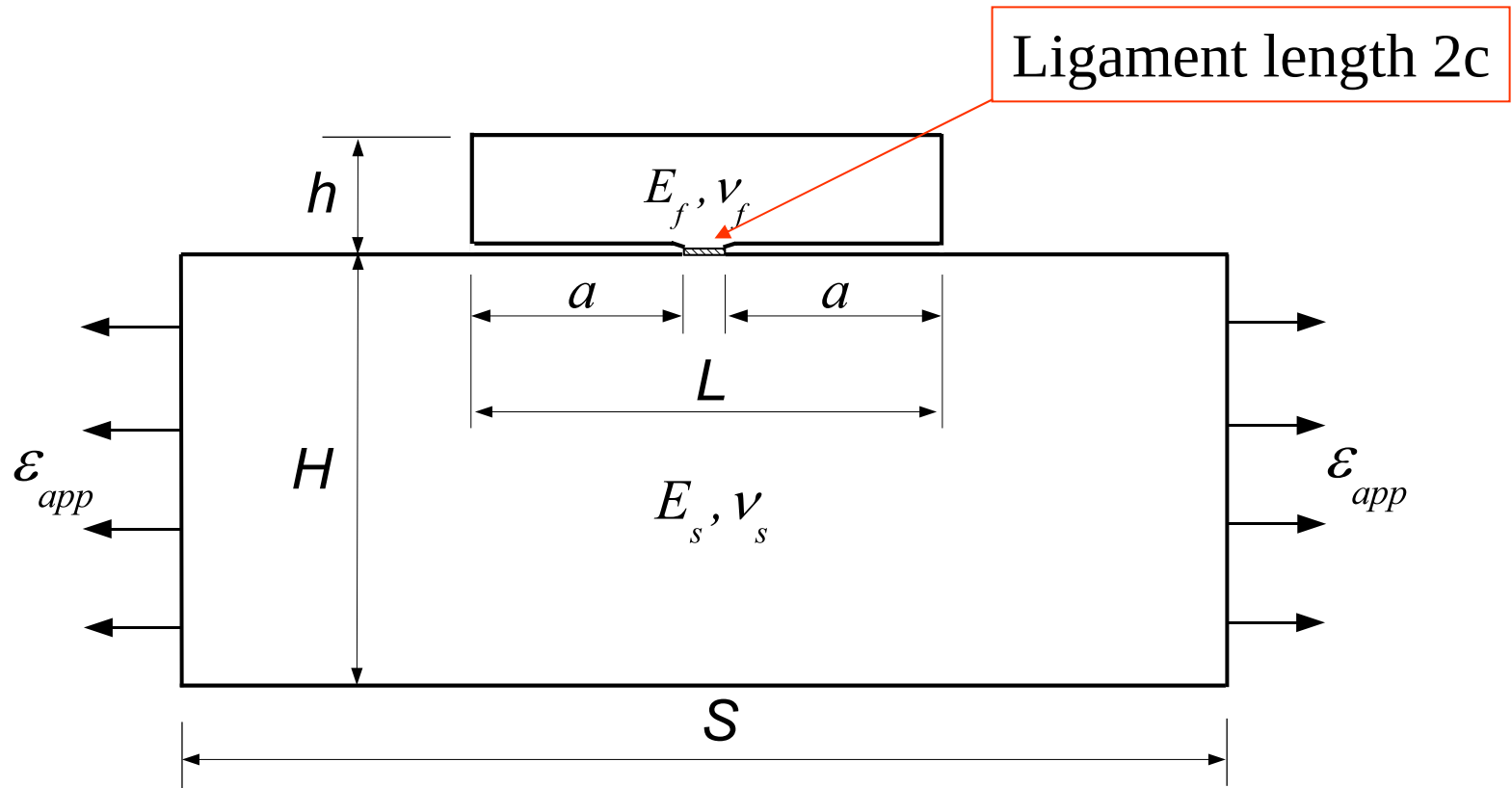
Steady state



$$G_{ss} = \frac{g}{2} E_f (\varepsilon_{appl})^2 h$$

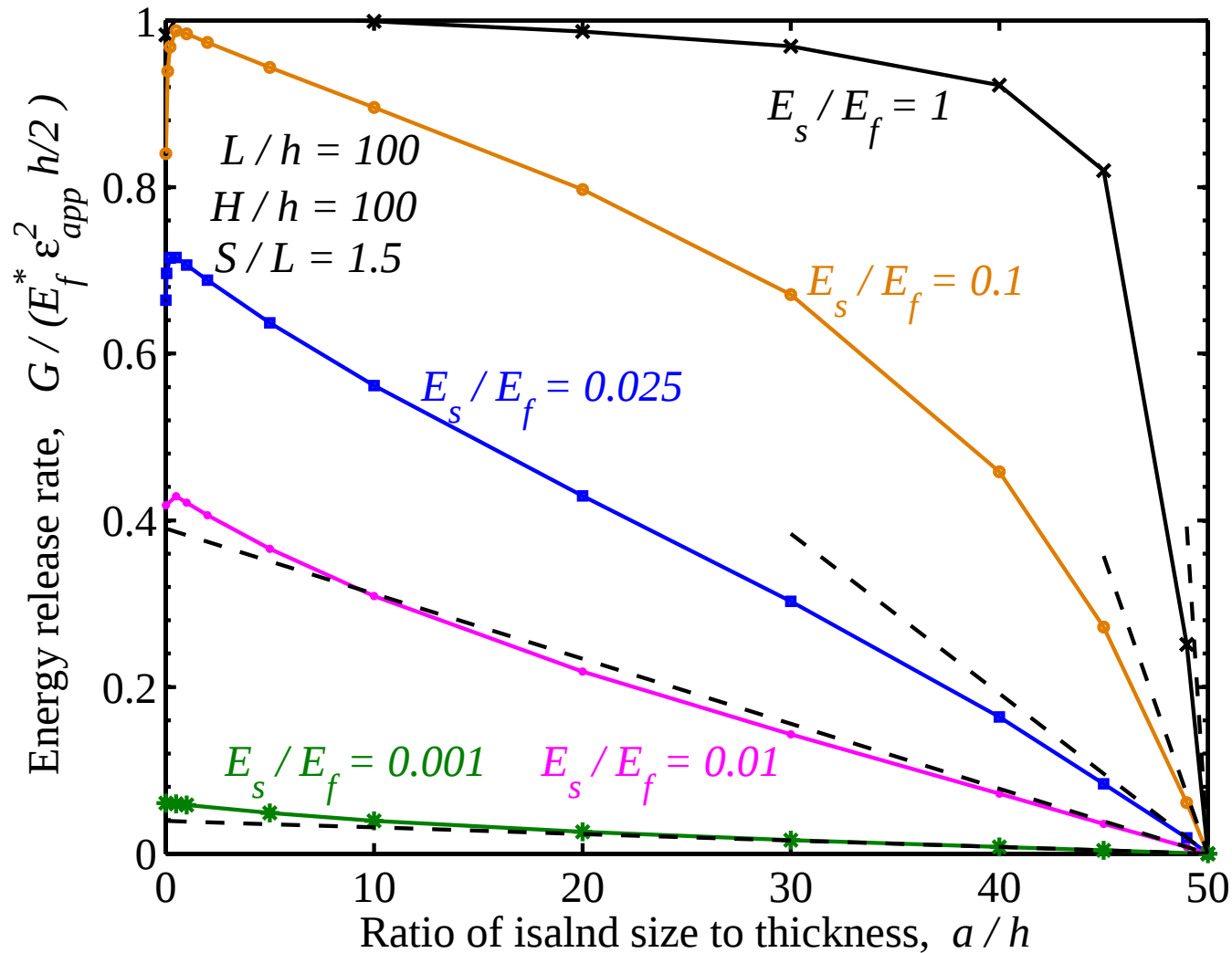


Converging debond

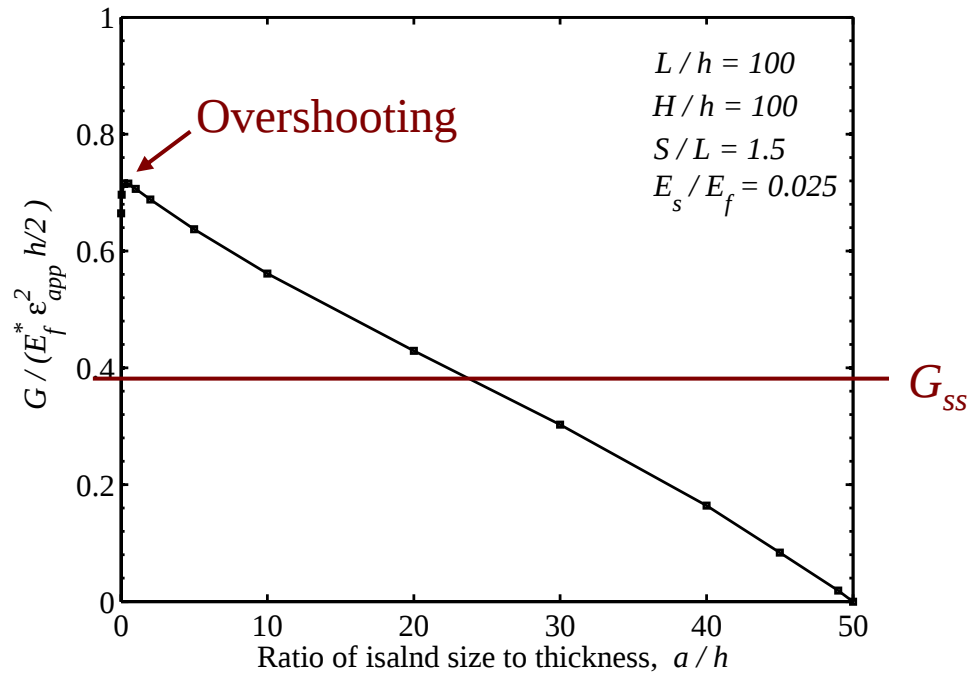
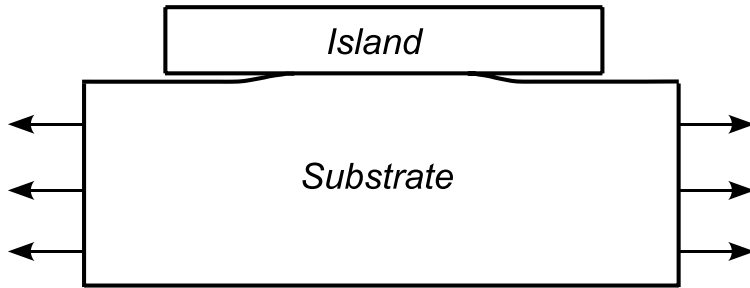


$$G = \frac{\pi}{8} \varepsilon_{app}^2 c \left(\frac{1}{E_s} + \frac{1}{E_f} \right)^{-1}$$

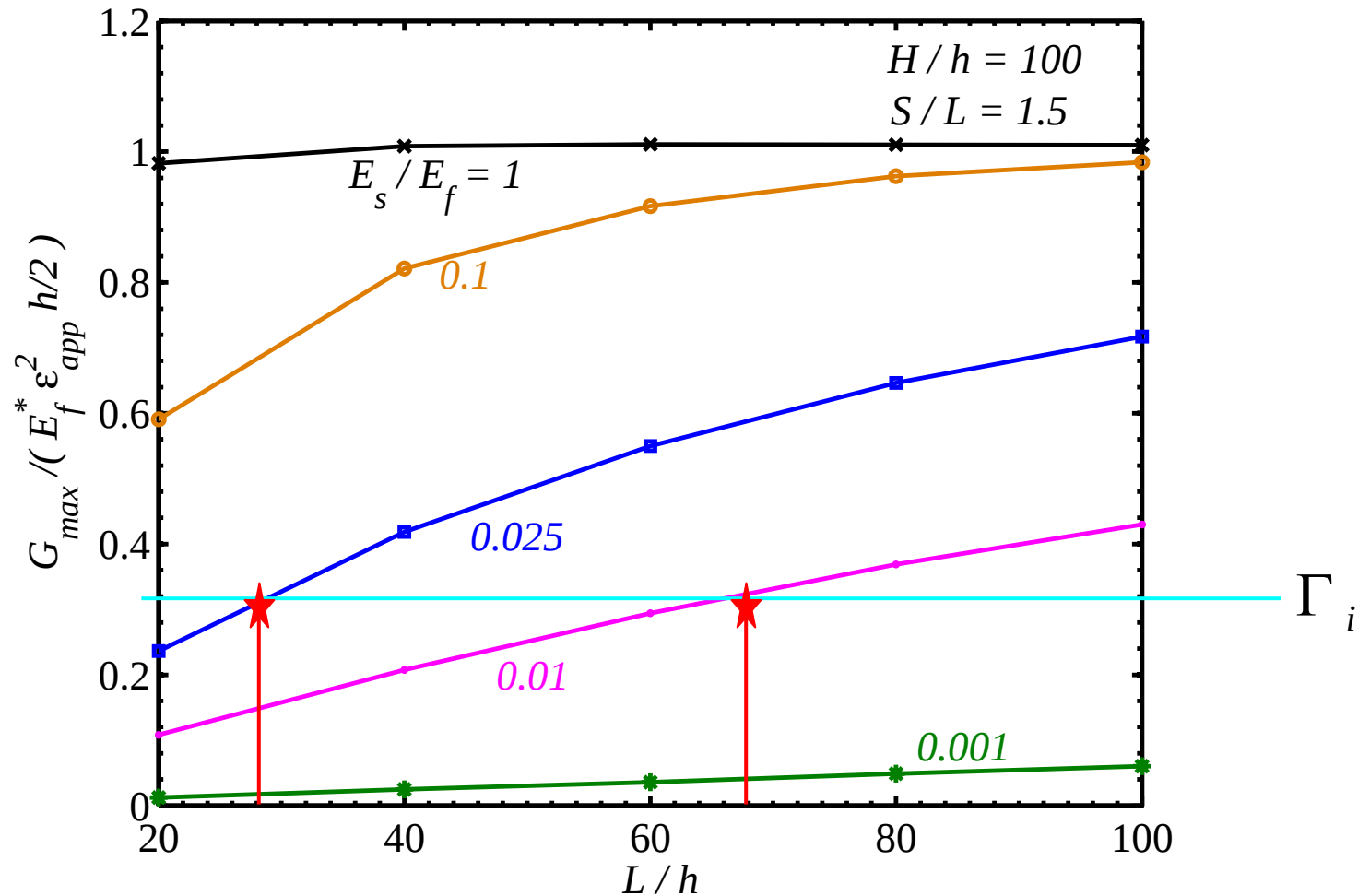
Effect of substrate compliance on $G(a)$



$G_{\max}$ overshoots G_{ss}



Critical island size



With the same interface toughness and the same applied strain, more compliant substrate allows larger critical island size

Summary

- Islands debond when exceeding critical size.
- $G_{\max}$ overshoots G_{ss} .
- Critical island size is large when the substrate is compliant.

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